

JC12 Rec'd PCT/PTC 19 OCT 2005

Docket No.: 071971-0388

PATENT**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

In re Application of	:	Customer Number: 20277
	:	
Masao UCHIDA, et al.	:	Confirmation Number: Not yet
assigned	:	
	:	
Application No.: Not yet assigned	:	Group Art Unit: Not yet assigned
	:	
Filed: October 19, 2005	:	Examiner: Not yet assigned
	:	
For: SEMICONDUCTOR DEVICE	:	

INFORMATION DISCLOSURE STATEMENT

Honorable Commissioner for Patents and Trademarks
Washington, D. C. 20231

Sir:

In accordance with the provisions of 37 C.F.R. 1.56, 1.97 and 1.98, the attention of the Patent and Trademark Office is hereby directed to the references listed on the attached form PTO-1449. It is respectfully requested that the references be expressly considered during the prosecution of this application, and that the references be made of record therein and appear among the "References Cited" on any patent to issue therefrom.

This Information Disclosure Statement is being filed with the application and no certification or fee is required.

A copy of the foreign search report is attached for the Examiner's information. Please note this is a PCT application in the entry of the National Phase in the U.S. and copies of the references cited were transmitted by WIPO and are believed to be in the file of the above identified application and readily available to the Examiner. Therefore it is believed that Applicants have met all requirements regarding duty of disclosure under 37

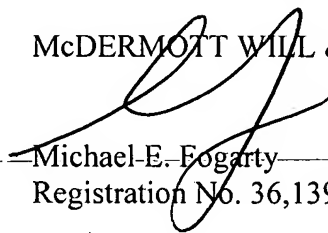
CFR 1.56. Acknowledgement and consideration of these documents are respectfully requested.

Since the Search Report was from the JPO Search Authority, copies of these references should have been supplied to the USPTO under the trilateral agreement and are believed to be in the file of the above identified application and readily available to the Examiner.

The relevance of WO 99/48153 (the International Publication of PCT/JP98/01185, cited in the specification), is discussed in the specification.

Respectfully submitted,

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**Please recognize our Customer No. 20277
as our correspondence address.**

INFORMATION DISCLOSURE CITATION IN AN APPLICATION				ATTY. DOCKET NO. 071971-0388		SERIAL NO. Not yet assigned <div style="font-size: 1.5em; font-weight: bold; margin-top: 5px;">10/553628</div>	
(PTO-1449)				APPLICANT Masao UCHIDA, et al.			
				FILING DATE October 19, 2005		GROUP Not yet assigned	

U.S. PATENT DOCUMENTS							
EXAMINER'S INITIALS	CITE NO.	Document Number Number-Kind Code ² (if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear		
		US 2003/0080384 A1			Corresponds to JP 2003-234301 A		
		US 5977564 A			Corresponds to JP 10-321854 A		
		US 6097039 A			Corresponds to JP 2001-517375 A		
		US					
		US					
		US					
		US					
		US					
		US					

FOREIGN PATENT DOCUMENTS							
EXAMINER'S INITIALS	CITE NO.	Foreign Patent Document Country Codes-Number +Kind Codes (if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines Where Relevant Figures Appear	Translation	
						Yes	No
		JP 2003-234301 A	08-22-2003	Matsushita Electric Industrial Co., Ltd.	Corresponds to US 2003/0080384 A1		
		JP 2003-209251 A	07-25-03	Japan Atomic Energy Research Institute			
		JP 10-321854 A	12-04-1998	Toshiba Corp.	Corresponds to US 5977564 A		
		JP 2000-294777 A	10-20-2000	Mitsubishi Electric Corp.			
		JP 2001-517375 A	10-02-2001	Siemens AG.	Corresponds to US 6097039 A		
		JP 2001-144288 A	05-25-2001	Denso Corp.			
		JP 2002-280381 A	09-27-2002	Fuji Electric Co., Ltd.			
		WO 99/48153	09-23-1999	HITACHI, LTD.			JAPAN (w/English Abstract)

OTHER ART (Including Author, Title, Date, Pertinent Pages, Etc.)			
EXAMINER'S INITIALS	CITE NO.	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	
		G.Y. CHUNG, et al., "Improved Invention Channel Mobility for 4H-SiC MOSFETs Following High Temperature Anneals in Nitric Oxide," <i>Electron Device Letters</i> , April 2001, pp 176-178, Vol 22, No. 4, IEEE	

EXAMINER	DATE CONSIDERED
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*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

1 Applicant's unique citation designation number (optional). 2 Applicant is to place a check mark here if English language Translation is attached.